

### The Big Deal:

- Ultra Flat Gain Response:  
± 0.2 dB over 800-1200 MHz
- Excellent Combination of gain,  
P1dB, IP3 and NF
- 50Ω Input and Output:  
no External Components Required



CASE STYLE: DL1636

### Product Overview:

YSF-122+ is an advanced amplifier module in a Mini-Circuits System In Package **MSiP™**. This module is fully matched to 50Ω in/out impedance and has built-in Input & Output DC block capacitors. It is enclosed in a 5 x 6 mm MCLP plastic package. The YSF-122+ uses E-PHEMT technology enabling it to work with a single positive supply voltage.

### Key Features

Feature	Advantages
Superior Gain Flatness ± 0.2dB	The YSF-122+ provides industry leading gain flatness over the full cellular communications L band (800-1200 MHz) making this ideal for use in applications where gain-flatness and repeatability are critical performance requirements.
High Gain	The YSF-122+ is a two-stage design with internal feedback and bias to provide flat 20 dB nominal gain, supporting applications where a single gain block must overcome large system losses such as long cable runs and lossy components.
Strong Combination of Performance	The YSF-122+ provides a strong combination of performance parameters including high gain (20 dB), high IP3 (+37 dBm) and P1dB (+20 dBm) and low noise figures (3.4 dB) that are difficult to achieve in a single stage design and available only in the YSF amplifier series.
Integrated Matching, DC Blocking and Bias in Small Package	The YSF-122+ includes all support circuits including: Matching, Bias and DC Blocking, all integrated into a single 5x6mm package making the total footprint equal to or smaller than most solutions.
Excellent Return Loss	The YSF-122+ includes integrated input and output matching and bias circuits to make this amplifier a simple, complete drop-in solution. The matching circuits provide excellent output return loss (17dB), and are designed to give optimal P1dB and IP3 performance in a 50Ω environment.
High Reverse Isolation	With 30 dB of reverse isolation – the YSF-122+ is an ideal gain block for use in integrated systems to minimize VSWR interactions resulting from cascading highly reflective components such as sharp filters.

#### Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.  
 B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.  
 C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp)



# Flat Gain Amplifier

0.8-1.2 GHz

## Product Features

- Matched 50-ohm surface mount amplifier
- High gain, 20 dB typ.
- Up to +20 dBm typ. output power
- High IP3, +37 dBm
- Low Noise Figure, 3.4 dB typ.
- High directivity, 32 dB isolation
- Internal Input & Output DC Block
- Separate terminal for DC



## YSF-122+

CASE STYLE: DL1636  
PRICE: \$2.69 ea. QTY. (20)

### +RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

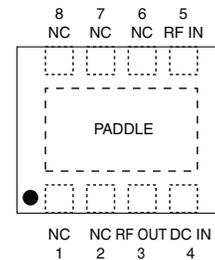
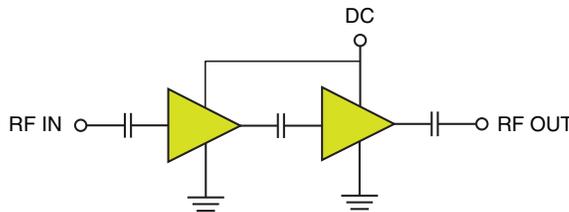
## Typical Applications

- Cellular
- Portable Wireless
- Receivers & transmitters
- Radar

## General Description

YSF-122+ is an advanced amplifier module in a Mini-Circuits System In Package **MSiP™**. This module is fully matched to 50Ω in/out impedance and has built-in Input & Output DC block capacitors. It is enclosed in a 5 x 6 mm MCLP plastic package. The YSF-122+ uses E-PHEMT\* technology enabling it to work with a single positive supply voltage.

### simplified schematic and pad description



Function	Pad Number	Description
RF-IN	5	RF Input
RF-OUT	3	RF Output
DC	4	DC Supply
GND	Paddle	Connected to ground
NOT USED	1,2,6,7,8	No internal connection

\*Enhancement mode Pseudomorphic High Electron Mobility Transistor

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**Electrical Specifications<sup>(1)</sup> at 25°C, Zo=50Ω unless noted**

Parameter	Condition (MHz)	Min.	Typ.	Max.	Units
Frequency Range		800		1200	MHz
Gain	800	18.1	20.1	22.1	dB
	1000	18.4	20.4	22.4	
	1200	18.3	20.3	22.3	
Gain Flatness			±0.2		dB
Input Return Loss	800		8.8		dB
	1000	9.0	11.0		
	1200		11.0		
Output Return Loss	800		13.0		dB
	1000	11.0	15.0		
	1200		17.3		
Reverse Isolation			32.0		dB
Output Power @ 1 dB compression	800		20.5		dBm
	1000	18.5	20.5		
	1200		20.4		
Output Power @ 3 dB compression			21.3		dBm
Output IP3	800		37.0		dBm
	1000	31.0	36.0		
	1200		36.0		
Noise Figure	800		3.5	4.4	dB
	1000		3.4		
	1200		3.4		
Device Operating Voltage			5		V
Device Operating Current			118	145	mA
Device Current Variation vs. Temperature <sup>(2)</sup>			2		μA/°C
Device Current Variation vs Voltage			0.002		mA/mV
Thermal Resistance, junction-to-ground lead <sup>(3)</sup>			56		°C/W

<sup>(1)</sup> Measured on Mini-Circuits Characterization test board TB-616+. See Characterization Test Circuit (Fig. 1)

<sup>(2)</sup> Δ(+85°C to -45°C)

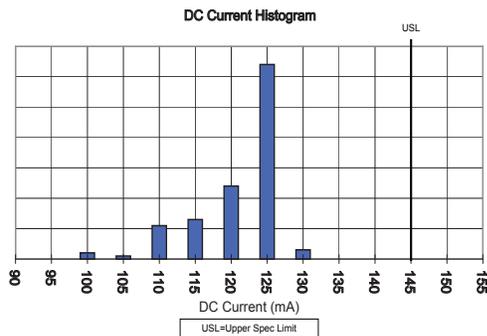
<sup>(3)</sup> Thermal Resistance=  $\frac{\text{Hot spot temperature} - \text{Ground lead temperature}}{\text{Power Dissipation}}$

**Absolute Maximum Ratings**

Parameter	Ratings	Units
Operating Temperature <sup>(4)</sup>	-40 to 85	°C
Storage Temperature	-65 to 150	°C
DC Voltage on Pad 4	7	V
Power Dissipation	1.5	W
Input Power	21	dBm

Note: Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

<sup>(4)</sup> Case is defined as ground paddle.

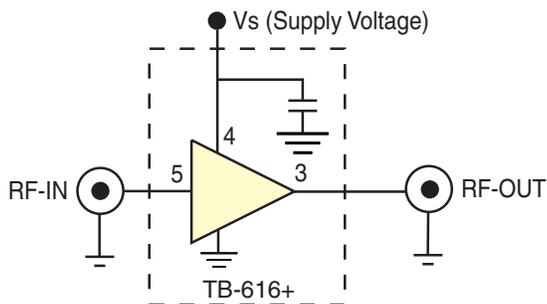


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### Characterization Test Circuit



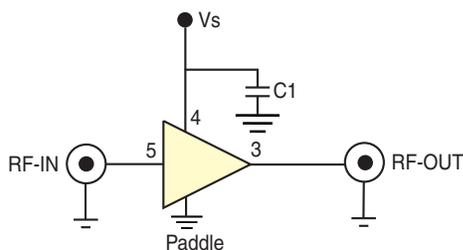
**Fig 1.** Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Fixture TB-616+) Gain, Return loss, Output power at 1dB compression (P1 dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

**Conditions:**

1. Gain: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 10 MHz apart, 2.5 dBm/tone at output.

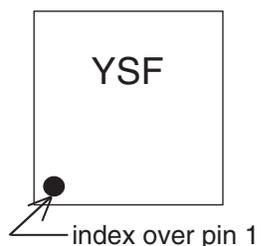
### Recommended Application Circuit

(refer to evaluation board for PCB Layout and component values)



**Fig 2.** Recommended Application Circuit

### Product Marking



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<b>Additional Detailed Technical Information</b>	
<i>additional information is available on our dash board. To access this information <a href="#">click here</a></i>	
<b>Performance Data</b>	Data Table
	Swept Graphs
	S-Parameter (S2P Files) Data Set (.zip file)
<b>Case Style</b>	DL1636 <i>Plastic package, exposed paddle, lead finish: tin/silver/nickel</i>
<b>Tape &amp; Reel</b> Standard quantities available on reel	F68 <i>7" reels with 20, 50, 100, 200, 500 or 1K devices. 13" reels with 2K, or 4K devices.</i>
<b>Suggested Layout for PCB Design</b>	PL-352
<b>Evaluation Board</b>	TB-616-2+
<b>Environmental Ratings</b>	ENV08T1

**ESD Rating**

Human Body Model (HBM): Class 1A in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (25V) in accordance with ANSI/ESD STM5.2-1999

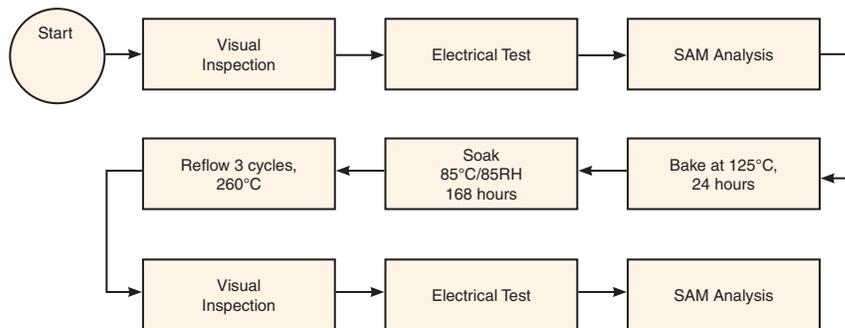


**Attention**  
 Observe precautions  
 for handling electrostatic  
 sensitive devices

**MSL Rating**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

**MSL Test Flow Chart**



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